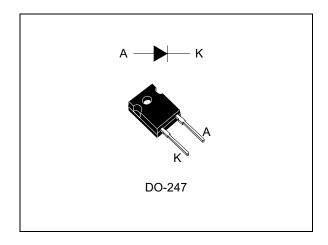
STTH6010-Y



Automotive ultrafast recovery - high voltage diode

Datasheet - production data



Features

- AEC-Q101 qualified
- Ultrafast, soft recovery
- Very low conduction and switching losses
- High frequency and/or high pulsed current operation
- High reverse voltage capability
- High junction temperature
- ECOPACK®2 compliant component

Description

The high quality design of this diode has produced a device with low leakage current, regularly reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability like automotive applications.

These diodes also fit into auxiliary functions such as snubber, bootstrap, and demagnetization applications.

The improved performance in low leakage current, and therefore thermal runaway guard band, is an immediate competitive advantage for this device.

Table 1. Device summary

I _{F(AV)}	60 A
V_{RRM}	1000 V
T _j (max.)	175 °C
V _F (typ)	1.3 V
t _{rr} (typ)	49 ns

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1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Paramete	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage	1000	V	
I _{F(RMS)}	Forward rms current		80	Α
I _{F(AV)}	Average forward current	60	Α	
I _{FRM}	Repetitive peak forward current $t_p = 5 \mu s$, $F = 5 kHz square$		450	Α
I _{FSM}	Surge non repetitive forward current	400	Α	
T _{stg}	Storage temperature range	-65 to + 175	°C	
Tj	Operating junction temperature range	-40 to + 175	°C	

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	0.78	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾ Reverse leakage current		T _j = 25 °C	$V_R = V_{RRM}$	-		20	μA
I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C	-		20	200		
		T _j = 25 °C		-		2.0	
V _F ⁽²⁾ Forward voltage drop	T _j = 100 °C	I _F = 60 A	-	1.4	1.8	V	
		T _j = 150 °C		-	1.3	1.7	

^{1.} Pulse test: $t_p = 5$ ms, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

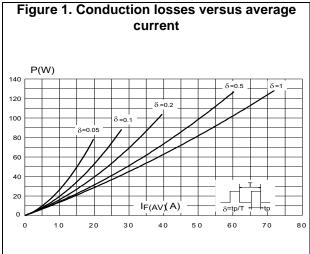
$$P = 1.3 \text{ x } I_{F(AV)} + 0.0067 I_{F}^{2}_{(RMS)}$$

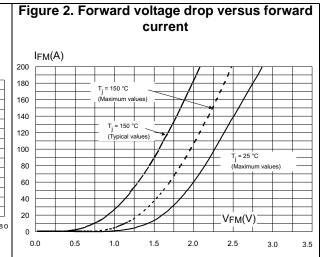
^{2.} Pulse test: t_p = 380 μ s, δ < 2%

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Table 5. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
		$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$	-		115	
t _{rr} Reverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -100 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$	-	61	80	ns	
		$I_F = 1 \text{ A, } dI_F/dt = -200 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$	-	49	65	
I _{RM}	Reverse recovery current	$I_F = 60 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s},$ $V_R = 600 \text{ V}, T_j = 125 ^{\circ}\text{C}$	-	31	40	А
S	Softness factor	$I_F = 60 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s},$ $V_R = 600 \text{ V}, T_j = 125 ^{\circ}\text{C}$	-	1		
t _{fr}	Forward recovery time $ \begin{aligned} I_F &= 60 \text{ A, } dI_F/dt = 100 \text{ A/}\mu\text{s,} \\ V_{FR} &= 1.5 \text{ x } V_{Fmax}, T_j = 25 \text{ °C} \end{aligned} $		-		750	ns
V _{FP}	Forward recovery voltage	$I_F = 60 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s},$ $T_j = 25 \text{ °C}$	-	4		V





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0

0

100 150

Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

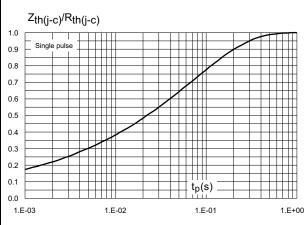


Figure 4. Peak reverse recovery current versus dl_F/dt (typical values)

Figure 5. Reverse recovery time versus dl_F/dt (typical values)

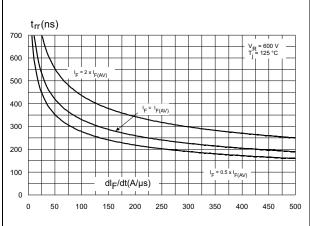


Figure 6. Reverse recovery charges versus dl_F/dt (typical values)

250

300 350

200

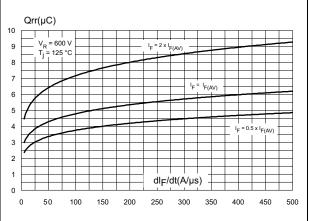


Figure 7. Softness factor versus dl_F/dt (typical values)

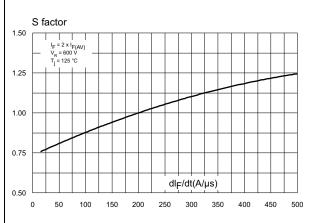
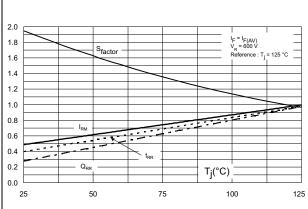


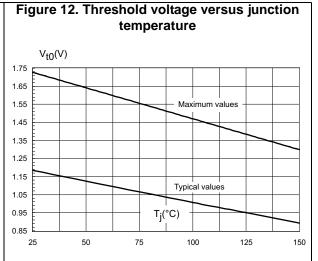
Figure 8. Relative variations of dynamic parameters versus junction temperature

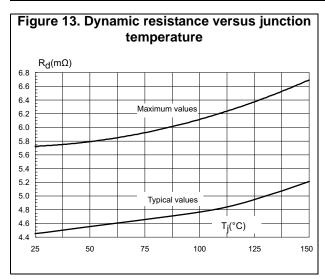


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Figure 9. Transient peak forward voltage Figure 10. Forward recovery times versus dl_F/dt (typical values) versus dl_F/dt (typical values) t_{fr}(ns) $V_{FP}(V)$ 1200 20 $I_F = I_{F(AV)}$ $V_{FR} = 1.5 \text{ x } V_{F}$ $T_j = 125 \text{ °C}$ I_F = I_{F(AV)} T_j = 125 °C 18 1000 16 14 12 800 10 600 6 400 $dI_F/dt(A/\mu s)$ dlF/dt(A/µs) 200 0 100 200 300 400 500

Figure 11. Junction capacitance versus reverse voltage applied (typical values) C(pF) $V_{t0}(V)$ 1000 1.75 V_{OSC} = 30 mV_{RMS} 1.65 1.55 1.45 1.35 100 1.25 1.15 1.05 0.95 $V_{R}(V)$ 10 0.85 25 50 1 0 1000





500

Package information STTH6010-Y

Package information 2

Epoxy meets UL94, V0

Cooling method: by conduction (C) Recommended torque value: 0.80 N·m

Maximum torque value: 1.0 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

DO-247 package information 2.1

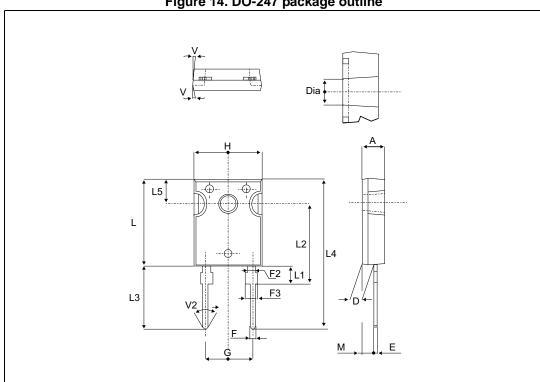


Figure 14. DO-247 package outline

Table 6. DO-247 package mechanical data

		Dimensions						
Ref.		Millimeters			Inches ⁽¹⁾			
	Тур.	Min.	Max.	Тур.	Min.	Max.		
Α		4.85	5.15		0.191	0.203		
D		2.20	2.60		0.086	0.102		
E		0.40	0.80		0.015	0.031		
F		1.00	1.40		0.039	0.055		
F2	2.00			0.078				
F3		2.00	2.40		0.078	0.094		
G	10.90			0.429				
Н		15.45	15.75		0.608	0.620		
L		19.85	20.15		0.781	0.793		
L1		3.70	4.30		0.145	0.169		
L2	18.50			0.728				
L3		14.20	14.80		0.559	0.582		
L4	34.60			1.362				
L5	5.50			0.216				
М		2.00	3.00		0.078	0.118		
V	5°			5°				
V2	60°			60°				
Dia.		3.55	3.65		0.139	0.143		

^{1.} Values in inches are converted from mm and rounded to 4 decimal digits.

Ordering information STTH6010-Y

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH6010WY	STTH6010WY	DO-247	4.4 g	30	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
04-Nov-2011	1	Initial release.
22-Apr-2015	2	Added Figure 12 and Figure 13. Document updated to current standard.

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